MBRF20200CT

Preferred Device

SWITCHMODE™ Schottky Power Rectifier

The SWITCHMODE Power Rectifier employs the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for use as rectifiers in very low-voltage, high-frequency switching power supplies, free wheeling diodes and polarity protection diodes.

- Highly Stable Oxide Passivated Junction
- Very Low Forward Voltage Drop
- Matched Dual Die Construction
- High Junction Temperature Capability
- High dv/dt Capability
- Excellent Ability to Withstand Reverse Avalanche Energy Transients
- Guardring for Stress Protection
- Epoxy Meets UL94, V_O at 1/8"
- Electrically Isolated. No Isolation Hardware Required.
- UL Recognized File #E69369

Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 units per plastic tube
- Marking: B20200

MAXIMUM RATINGS

Please See the Table on the Following Page

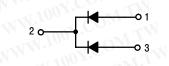
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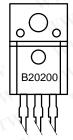
SCHOTTKY BARRIER RECTIFIER 20 AMPERES 200 VOLTS





ISOLATED TO-220 CASE 221D STYLE 3

MARKING DIAGRAM



B20200 = Device Code

ORDERING INFORMATION

Device	Package	Shipping
MBRF20200CT	TO-220	50 Units/Rail

Preferred devices are recommended choices for future use and best overall value.

	COMT	W	Ţ
Rating	Symbol	Value	Unit
eak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	200	Volts
verage Rectified Forward CurrentPer Leg(Rated V_R) $T_C = 125^{\circ}C$ Per Package	I _{F(AV)}	10 20	Amps
eak Repetitive Forward Current, Per Leg (Rated V _R , Square Wave, 20 kHz) T _C = 90°C	IFRM	20	Amps
onrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	150	Amps
eak Repetitive Reverse Surge Current (2.0 μs, 1.0 kHz)	I _{RRM}	1.0	Amp
perating Junction Temperature and Storage Temperature	T _J , T _{stg}	-65 to +150	°C
bltage Rate of Change (Rated V _R)	dv/dt	10,000	V/µs
ERMAL CHARACTERISTICS (Per Leg)	WW.IU	N.CON.	
nermal Resistance — Junction to Case	$R_{\theta JC}$	3.5	°C/W
ECTRICAL CHARACTERISTICS (Per Leg)	WITT	1001. COM.1	Ţ
Rating	Symbol	Max	Unit
aximum Instantaneous Forward Voltage (Note 1.) ($i_F = 10 \text{ Amp}, T_C = 25^{\circ}\text{C}$) ($i_F = 10 \text{ Amp}, T_C = 125^{\circ}\text{C}$) ($i_F = 20 \text{ Amp}, T_C = 25^{\circ}\text{C}$) ($i_F = 20 \text{ Amp}, T_C = 125^{\circ}\text{C}$)	VF	0.9 0.8 1.0 0.9	Volts
aximum Instantaneous Reverse Current (Note 1.) (Rated dc Voltage, $T_C = 25^{\circ}C$) (Rated dc Voltage, $T_C = 125^{\circ}C$)	i _R	1.0 50	mA
NAMIC CHARACTERISTICS (Per Leg) apacitance ($V_R = -5.0 V$, $T_C = 25^{\circ}C$, Freq. = 1.0 MHz)	CT	500	pF
Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%			
	NP .	T _J = 150°C -	TO T
	T _J = 125	°C	
$T_J = 150^{\circ}C$ \rightarrow $3 \cdot 100$	CON-1	- T _J = 100°C	
			100 F. ON
			0.
	1.	TH TH	<u>-101</u>
$T_{J} = 125^{\circ}C$			CV
$T_{J} = 125^{\circ}C$	1051.CO		
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	T _J = 25°C		
5 T _J = 100°C		1.1	
5 T _J = 100°C 0.01 0 20	40 60	80 100 120 140 1	160 180 200
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	40 60 V _R , RE	1.1	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	40 60 V _R , RE	80 100 120 140 T VERSE CURRENT (VOLTS)	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	40 60 V _R , RE gure 2. Typic	80 100 120 140 VERSE CURRENT (VOLTS) cal Reverse Current (F	Per Leg)
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	40 60 V _R , RE gure 2. Typic	80 100 120 140 T VERSE CURRENT (VOLTS)	Per Leg) 3170

MBRF20200CT

TEST CONDITIONS FOR ISOLATION TESTS*

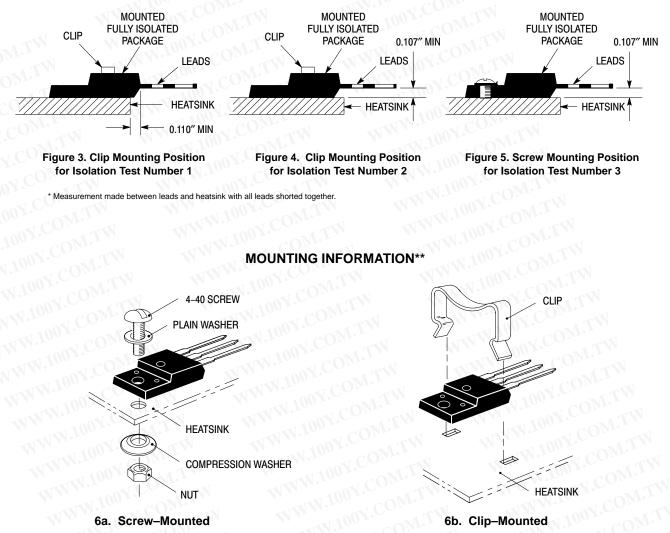


Figure 6. Typical Mounting Techniques

Laboratory tests on a limited number of samples indicate, when using the screw and compression washer mounting technique, a screw torque of 6 to 8 in \cdot lbs is sufficient to provide maximum power dissipation capability. The compression washer helps to maintain a constant pressure on the package over time and during large temperature excursions.

Destructive laboratory tests show that using a hex head 4–40 screw, without washers, and applying a torque in excess of 20 in \cdot lbs will cause the plastic to crack around the mounting hole, resulting in a loss of isolation capability.

Additional tests on slotted 4–40 screws indicate that the screw slot fails between 15 to 20 in \cdot lbs without adversely affecting the package. However, in order to positively ensure the package integrity of the fully isolated device, ON Semiconductor does not recommend exceeding 10 in \cdot lbs of mounting torque under any mounting conditions.

**For more information about mounting power semiconductors see Application Note AN1040.

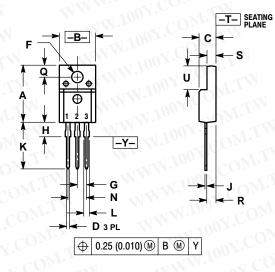
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MBRF20200CT

PACKAGE DIMENSIONS

TO-220 FULLPAK CASE 221D-02 **ISSUE D**



NOTES: DIMENSIONING AND TOLERANCING PER ANSI Y14.5M. 1982. 2.

CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS		
	MIN	MAX	MIN	MAX	
Α	0.621	0.629	15.78	15.97	
В	0.394	0.402	10.01	10.21	
C	0.181	0.189	4.60	4.80	
D	0.026	0.034	0.67	0.86	
F	0.121	0.129	3.08	3.27	
G	0.100 BSC		2.54 BSC		
H	0.123	0.129	3.13	3.27	
J	0.018	0.025	0.46	0.64	
K	0.500	0.562	12.70	14.27	
τ.	0.045	0.060	1.14	1.52	
Ν	0.200 BSC		5.08 BSC		
Q	0.126	0.134	3.21	3.40	
R	0.107	0.111	2.72	2.81	
S	0.096	0.104	2.44	2.64	
U	0.259	0.267	6.58	6.78	

ANODE PIN 1. 2. CATHODE 3. ANODE

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